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PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Attn: OIPE

Izumi FUSEGAWA et al.

Group Art Unit: 1722

Application No.: 10/568,186

Docket No.: 126961

Filed: February 13, 2006

For: METHOD FOR PRODUCING A SINGLE CRYSTAL AND SILICON SINGLE
CRYSTAL WAFER

REQUEST FOR CORRECTION OF PALM RECORDS

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

Attached is a photocopy of the original filing receipt on which errors have been corrected in red. These errors are being brought to the attention of the Patent and Trademark Office so that it may correct its records. A Supplemental Application Data Sheet is attached.

Respectfully submitted,

William P. Berridge
Registration No. 30,024

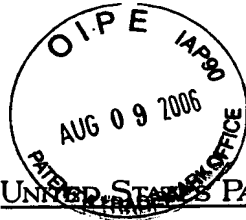
Linda M. Saltiel
Registration No. 51,122

WPB:LMS/nxy

Date: August 9, 2006

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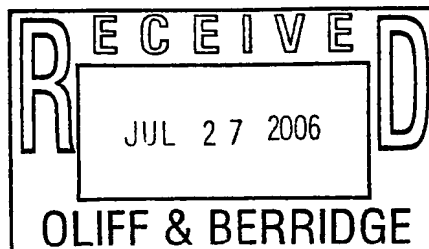
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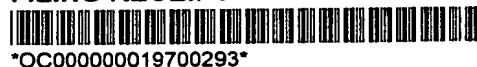
APPL NO.	FILING OR 371 (c) DATE	ART UNIT	FIL FEE REC'D	ATTY. DOCKET NO	DRAWINGS	TOT CLMS	IND CLMS
10/568,186	03/03/2006	1722	1030	126961	5	17	2

25944
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CONFIRMATION NO. 5592

FILING RECEIPT



OC000000019700293

Date Mailed: 07/21/2006

Receipt is acknowledged of this regular Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please mail to the Commissioner for Patents P.O. Box 1450 Alexandria Va 22313-1450. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Applicant(s)

Izumi Fusegawa, Fukushima, JAPAN;
 Nobuaki Mitamura, Fukushima, JAPAN; ~~Nobuaki Mitamura~~
 Takahiro Yanagimachi, Fukushima, JAPAN;

Assignment For Published Patent Application

Shin-Etsu Handotai Co., Ltd., Chiyoda-ku, JAPAN
 Tokyo

Power of Attorney: The patent practitioners associated with Customer Number 25944.

Domestic Priority data as claimed by applicant

This application is a 371 of PCT/JP04/11685 08/13/2004

Foreign Applications

2003-246037

JAPAN 2003296657 08/20/2003

If Required, Foreign Filing License Granted: 07/20/2006

The country code and number of your priority application, to be used for filing abroad under the Paris Convention, is **US10/568,186**

Projected Publication Date: 10/26/2006

Non-Publication Request: No

Early Publication Request: No

Title *Method for Producing a single crystal and silicon single crystal wafer*
~~Process for producing single crystal and silicon crystal wafer~~

Preliminary Class

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OLIFF & BERRIDGE, PLC
ATTORNEYS AT LAW

Supplemental Application Data Sheet

Applicant Information

Applicant Authority type::	Inventor
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Country of Residence::	Japan

Correspondence Information

Correspondence Customer Number::	25944
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Application Information

Application Type::	National Phase
Subject Matter::	Utility
CD-ROM or CD-R::	None

Title::	METHOD FOR PRODUCING A SINGLE CRYSTAL AND SILICON SINGLE CRYSTAL WAFER
Attorney Docket Number::	126961
Suggested Drawing Figure::	1
Total Drawing Sheets::	5
Small Entity::	No

Representative Information

Attorneys associated with Customer No. 25944.

Domestic Priority Information			
Application::	Continuity Type::	Parent Application::	Parent Filing Date::
This Application is a	National Stage of	PCT/JP2004/011685	08/13/04
Foreign Priority Information			
Country::	Application Number::	Filing Date::	Priority Claimed::
Japan	2003-296837	08/20/03	Yes
Assignee Information			
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